

SANYO Semiconductors **DATA SHEET**

LA6548NH — For CD Players and Recorders Four-Channel Driver IC

Overview

The LA6548NH is a four-channel driver IC for CD players and recorders (four BTL amplifier channels).

Functions

- Four BTL connection power amplifier channels
- IO max 0.7A
- Built-in level shifters
- Muting circuit (on/off control of all outputs)
 (This circuit applies to the BTL amplifier circuits. It does not control operation of the regulator.)
- Built-in regulator (provides a 3.3V output using an external pnp transistor)
- Thermal protection circuit (thermal shutdown circuit)

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC} max		14	V
Maximum output current	I _O max	For each of the channel 1 to 4 outputs	0.7	Α
Maximum input voltage	VIN		13	V
Muting pin application voltage	VMUTE		13	V
Allowable power dissipation	Pd max	Independent IC	0.8	W
		Specified circuit board *	1.8	W
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

^{*} Specified substrate: 76.1mm×114.3mm×1.6mm, glass epoxy board.

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Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V _{CC} 1		4.6 to 13	V
Supply voltage 2	V _{CC} 2	Only used by the BTL amplifiers	3.9 to 13	V
		(Not used by the 3.3V regulator circuit)		

$\textbf{Electrical Characteristics} \ at \ Ta = 25^{\circ}C, \ V_{CC}1 = V_{CC}2 = 6V, \ VREF = 1.65V, \ unless \ otherwise \ specified.$

Б		Ratings			11-26		
Parameter	Symbol	Conditions	min	typ	max	Unit	
Overall Characteristics	Overall Characteristics						
No-load current drain, on state	lo-load current drain, on state I _{CC} ON All outputs on, MUTE : high			20	40	mA	
No-load current drain, off state	I _{CC} OFF	All outputs off, MUTE : low		15	35	mA	
Thermal shutdown circuit operating temperature	(13 3 11 11)		150	175	200	°C	
Output Amplifier Block							
Output offset voltage	VOFF	The voltage difference between each of the + or - outputs.	-50		50	mV	
VREF input voltage range	V _{IN} VREF		1.3		V _{CC} -1.5	V	
Output voltage V_{O} The voltage across the outputs when R_{L} = 8Ω		,	2.6	3		V	
Voltage gain, input to output	VG	The voltage gain from an input to the corresponding +/- outputs.*2		9		dB	
Slew rate				0.15		V/μs	
Muting on voltage VMUTE		The voltage at which the output on/off state changes		1.2		V	
Power Supply Block (Using a 2S	Power Supply Block (Using a 2SB632K)						
3.3V power supply voltage		I _O = 200mA	3.13	3.3	3.47	V	
Line regulation	ne regulation ΔV_{OLIN} 4.6V \leq V _{CC} \leq 12V		40	100	mV		
Load regulation	ΔV_{O} LOAD	5mA ≤ I _O ≤ 200mA		50	150	mV	
Reset Block							
RESET pin high-level voltage	V _O RH		3.08	3.25	3.42	V	
RESET pin low-level voltage V _O RL ISRL = 2mA, Cd-GND		ISRL = 2mA, Cd-GND		100	200	mV	
RESET pin threshold voltage V _{RT}		*4		2.8		V	
RESET pin hysteresis	V _{HYS}	*5	40	80	160	mV	
RESET pin output delay time td		Cd = 0.1μF		10		ms	

^{*1 :} These parameters are not tested.

 $^{^{\}star}2$: The gain from input to output when only the $V_{\mbox{\footnotesize{IN}}}{}^{\star}$ pins are used.

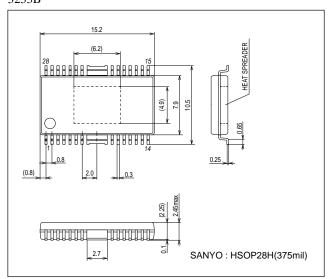
^{*3:} The MUTE pin voltage when the output changes between the on and off states. When the MUTE pin is high, all the BTL amplifiers will be on, and the when MUTE is low, all the BTL amplifiers will be off.

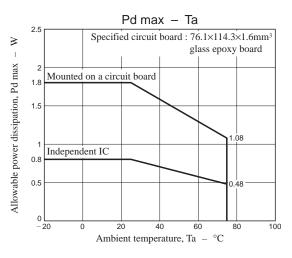
^{*4 :} The 3.3V regulator voltage when the RESET pin goes from high to low.

^{*5 :} The 3.3V regulator voltage difference between the RESET pin going from high to low the RESET pin going from low to high. That is, the hysteresis.

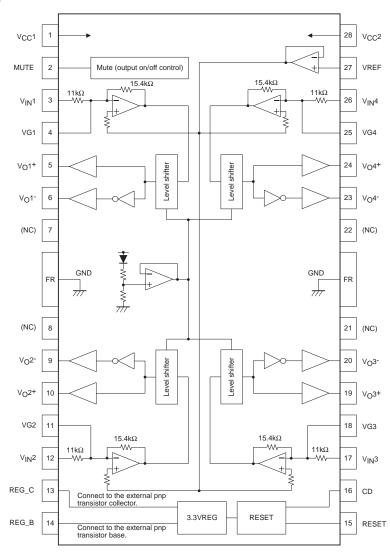
Package Dimensions

unit : mm (typ) 3233B





Block Diagram



LA6548NH

Pin Functions

Pin No.	Pin	Description	
1	V _{CC} 1	Power supply (This pin is shorted to V _{CC} 2 (pin 28)	
2	MUTE	Output on/off control	
3	V _{IN} 1	Channel 1 input	
4	VG1	Channel 1 input (Gain setting)	
5	V _O 1+	Channel 1 output (+)	
6	V _O 1⁻	Channel 1 output (-)	
7	(NC)	(This pin must not be used.)	
8	(NC)	(This pin must not be used.)	
9	V _O 2 ⁻	Channel 2 output (-)	
10	V _O 2+	Channel 2 output (+)	
11	VG2	Channel 2 input (Gain setting)	
12	V _{IN} 2	Channel 2 input	
13	REG_C	Connect this pin to the external pnp transistor collector. (This is the 3.3V regulator output)	
14	REG_B	Connect this pin to the external pnp transistor base.	
15	RESET	Reset output	
16	CD	Connection for the reset delay time setting capacitor	
17	V _{IN} 3	Channel 3 input	
18	VG3	Channel 3 input (Gain setting)	
19	V _O 3+	Channel 3 output (+)	
20	V _O 3⁻	Channel 3 output (-)	
21	(NC)	(This pin must not be used.)	
22	(NC)	(This pin must not be used.)	
23	V _O 4⁻	Channel 4 output (-)	
24	V _O 4+	Channel 4 output (+)	
25	VG4	Channel 4 input (Gain setting)	
26	V _{IN} 4	Channel 4 input	
27	VREF	Reference voltage input	
28	V _{CC} 2	Power supply (This pin is shorted to V _{CC} 1 (pin 1)	

Equivalent Circuits

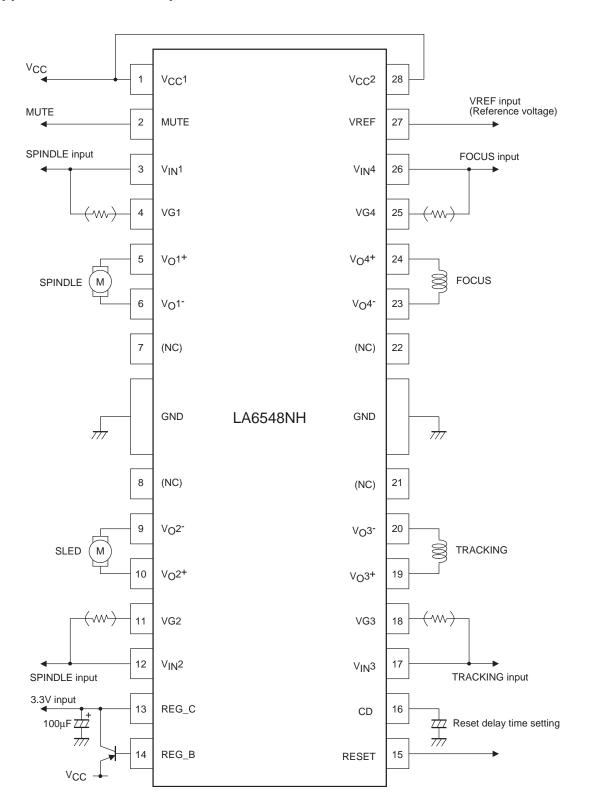
Pin No.	Pin	Description	Equivalent circuit
3 4 12 11 17 18 26 25	VIN1 VG1 VIN2 VG2 VIN3 VG3 VIN4 VG4	Input pins.	VING* VIN* VCC GND \$11kΩ VCC GND \$11kΩ
5 6 10 9 19 20 24 23	V _O 1+ V _O 1- V _O 2+ V _O 2- V _O 3+ V _O 3- V _O 4+ V _O 4-	Output pins.	VCC V CC

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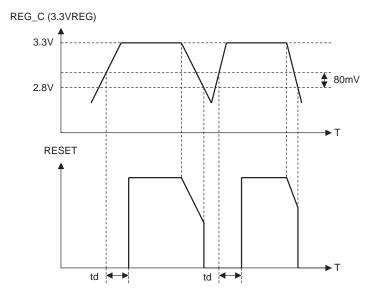
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Pin No.	Pin	Description	Equivalent circuit			
2	MUTE	Muting control input. The outputs will be on when the MUTE pin is at the high level. The outputs will be off when the MUTE pin is at the low level; in particular, the outputs go to the high-impedance state at this time.	MUTE $40k\Omega$ $30k\Omega$			
27	VREF	Reference voltage input.	VCC GND VCC			
15	RESET	Reset output. When REG C (3.3VREG) is high, RESET will be high. When REG C (3.3VREG) is low, RESET will be low. Details of Operating voltage see section Reset operation.	REG_C (3.3VREG) RESET GND GND			
16	CD	Reset output delay time setting. The delay time until the point the reset output switches from low to high is set by the capacitor connected between this pin and ground. Reference to Reset operation.	GND CD GND			

Application Circuit Example



Reset Operation



- *1: td is the delay time. It is set by an external capacitor connected between the CD pin and ground).
- *2 : The voltage at which RESET changes state is a typical value (voltage).

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